Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.120			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.150			
I _D (A)	1.7			
Configuration	Single			
Package	SC-70			

FEATURES

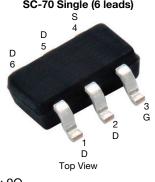
- TrenchFET® power MOSFET
- AEC-Q101 qualified d
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN FREE





Marking Code: 90

	D 9
G o —	

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 ^{\circ}C$, unless	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current ^a	T _C = 25 °C	I _D	1.7		
Continuous Drain Current -	T _C = 125 °C	ıD	1.7		
Continuous Source Current (Diode Conduction) ^a		Is	1.7	Α	
Pulsed Drain Current ^b		I _{DM}	6.7		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	10		
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	5	mJ	
Mariana Baran Birahari ah	T _C = 25 °C	P_{D}	3.3	W	
Maximum Power Dissipation ^b	T _C = 125 °C	FD	1.1	VV	
Operating Junction and Storage Temperature R	ange	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount c	R_{thJA}	125	°C/W
Junction-to-Foot (Drain)		R_{thJF}	45	C/ VV

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		1		ı		ı		
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} =	= 0 V, I _D = 250 μA	60	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2	2.5	V	
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		V _{GS} = 0 V	V _{DS} = 60 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	10	-	-	Α	
		V _{GS} = 10 V	I _D = 3.8 A	-	0.085	0.120		
Drain-Source On-State Resistance ^a	В	V _{GS} = 10 V	I _D = 3.8 A, T _J = 125 °C	-	-	0.200	Ω	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 3.8 A, T _J = 175 °C	-	-	0.240		
		V _{GS} = 4.5 V	I _D = 3.1 A	-	0.095	0.150		
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 1.8 A		-	6	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}			-	275	344		
Output Capacitance	C _{oss}	V _{GS} = 0 V V _{DS} = 15 V, f = 1 MHz		-	34	42	pF	
Reverse Transfer Capacitance	C _{rss}			-	13	17		
Total Gate Charge ^c	Q_g			-	4.4	5.5		
Gate-Source Charge	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_D = 3.8 \text{ A}$	-	0.7	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	1.3	-		
Gate Resistance	R_g	f = 1 MHz		2.1	4.1	6.2	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	5.8	7.3		
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 3.9 \Omega$ $I_{D} \cong 3.8 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	23	29	- ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	10	13		
Fall Time ^c	t _f			-	30	39		
Source-Drain Diode Ratings and Chara	ecteristics b							
Pulsed Current ^a	I _{SM}			-	-	11	Α	
Forward Voltage	V _{SD}	I _F = 1.8 A, V _{GS} = 0 V		_	0.8	1.2	V	

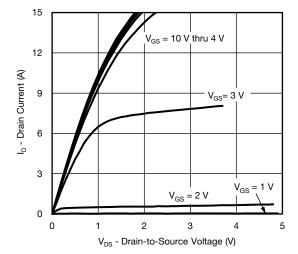
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

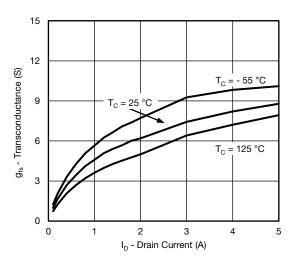
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



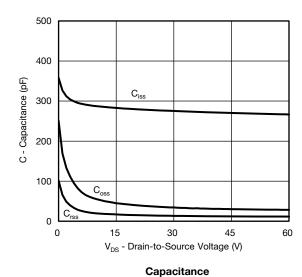
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

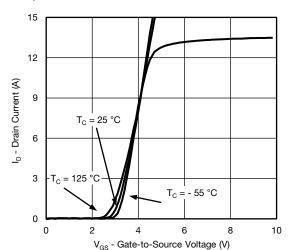


Output Characteristics

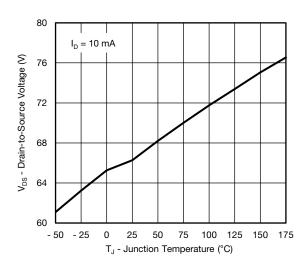


Transconductance

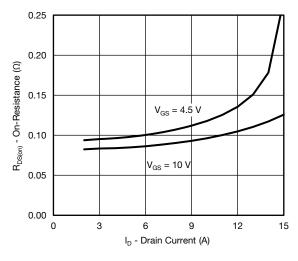




Transfer Characteristics



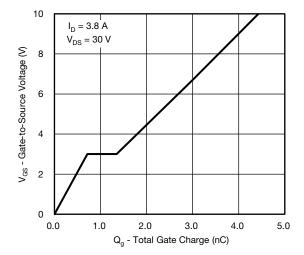
Drain Source Breakdown vs. Junction Temperature



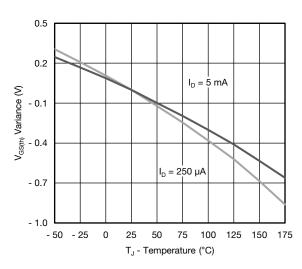
On-Resistance vs. Drain Current



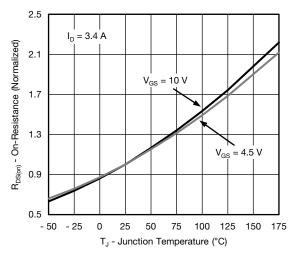
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



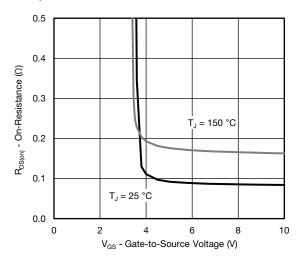
Gate Charge



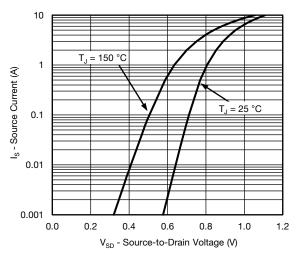
Threshold Voltage



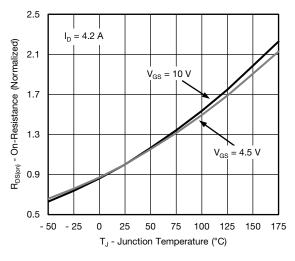
On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



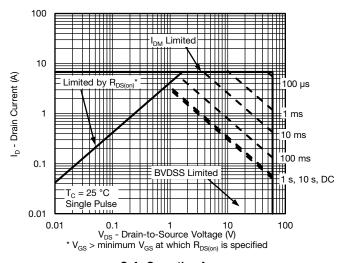
Source Drain Diode Forward Voltage



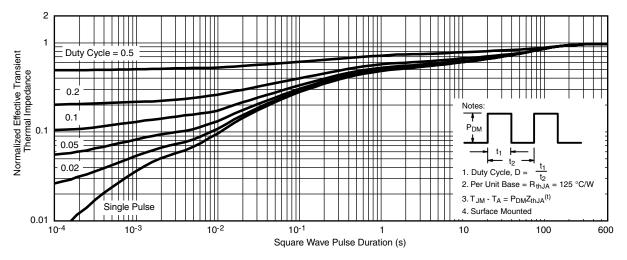
On-Resistance vs. Junction Temperature

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THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)

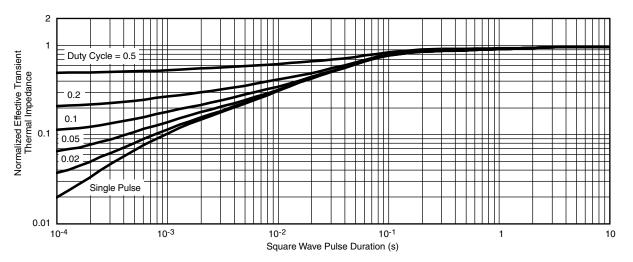


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65884.





Vishay Siliconix

SC-70

Ordering codes for the SQ rugged series power MOSFETs in the SC-70 package:

DATASHEET PART NUMBER	OLD ORDERING CODE a	NEW ORDERING CODE
SQ1421EEH	SQ1421EEH-T1-GE3	SQ1421EEH-T1_GE3
SQ1431EH	SQ1431EH-T1-GE3	SQ1431EH-T1_GE3
SQ1440EH	-	SQ1440EH-T1_GE3
SQ1470AEH	-	SQ1470AEH-T1_GE3
SQ1539EH	-	SQ1539EH-T1_GE3
SQ1563AEH	-	SQ1563AEH-T1_GE3
SQ1902AEL	-	SQ1902AEL-T1_GE3
SQ1912AEEH	-	SQ1912AEEH-T1_GE3

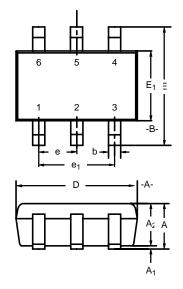
Note

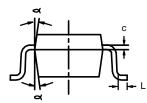
a. Old ordering code is obsolete and no longer valid for new orders





SC-70: 6-LEADS

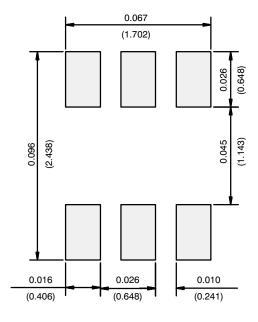




	MIL	LIMET	ERS	INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	-	1.10	0.035	_	0.043
A ₁	-	-	0.10	-	-	0.004
A_2	0.80	-	1.00	0.031	-	0.039
b	0.15	-	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	_	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Ε	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65BSC			0.026BSC	;
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
9	7°Nom				7°Nom	



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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